High-pressure Synthesis of Strontium Hexasilicide

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The binary phase SrSi_6 was prepared at a pressure of 10(1) GPa and a temperature of 1520(150) K. Single crystal refinements and powder diffraction data reveal that the compound crystallizes in the orthorhombic crystal system (*Cmcm*, a = 4.4692(4), b = 10.256(1), c = 11.698(1)Å) and is isopointal to EuGa₂Ge₄ and EuSi₆. Exothermic decomposition of the compound into SrSi₂ and Si at 797 K and ambient pressure indicates that the compound is a metastable high-pressure phase. Analysis of the chemical bonding using the electron localization function and calculated charge densities reveals covalent bonding within the polyanion of four-bonded silicon atoms. Strontium cations are enclosed in the 3D net resulting in an electron balance $\text{Sr}^{2+}[\text{Si}^0]_6^{2-}$. In the electronic density of states the excess electrons of the framework are assigned to a filling of antibonding bands. SrSi₆ is a metallic conductor with an electrical resistivity of $\rho \approx 250 \ \mu\Omega \cdot \text{cm}$ at 300 K. Magnetization measurements indicate diamagnetic behaviour ($\chi_0 = -50 \cdot 10^{-6} \text{ emu} \cdot \text{mol}^{-1}$).

Key words: Strontium, Silicon, High Pressure, Zintl Phase